LDMOS 1-stage integrated Doherty MMIC Rev. 2 — 29 January 2021

Product profile 1.

1.1 General description

The BLM9D0910-05AM is a 1-stage 5 W fully integrated Doherty MMIC solution using Ampleon's state of the art GEN9 LDMOS technology. The carrier and peaking device, input splitter and output combiner are integrated in a single package. This multiband device is perfectly suited as a device in the frequency range from 859 MHz to 960 MHz. Available in LGA outline.

Table 1. Performance

Typical RF performance at $T_{case} = 25 \ ^{\circ}C$; $I_{Dq} = 15 \ mA$ (driver and final stages) in a demo circuit; $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.55 V.$

Test signal	f	V _{DS}	P _{L(AV)}	G _p	ησ	
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
single carrier W-CDMA ^[1]	915	28	0.63	18.5	40	-32.5

[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

- Integrated input splitter
- Integrated output combiner
- Very high efficiency
- Designed for broadband operation (frequency 859 MHz to 960 MHz)
- Independent control of carrier and peaking bias
- Integrated ESD protection
- Excellent thermal stability
- High power gain, input and output matched to impedance 50 Ω
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

RF power MMIC for multi-carrier and multi-standard GSM, W-CDMA, LTE and NR small cell base stations in the 859 MHz to 960 MHz frequency range

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2. Pinning information

2.1 Pinning



2.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
V _{GS_P}	1	gate-source voltage of peaking
GND	2	ground
GND	3	ground
RFin	4	RF input
GND	5	ground
GND	6	ground
V _{DS1_P}	7	drain-source voltage of peaking driver
GND	8	ground
V _{DS2}	9	drain-source voltage of final stages
GND	10	ground
GND	11	ground
RFout	12	RF output
GND	13	ground
GND	14	ground
GND	15	ground
GND	16	ground
GND	17	ground
GND	18	ground

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Table 2. Pin descriptioncontinued				
Symbol		Pin	Description	
V _{DS1_C}		19	drain-source voltage of carrier driver	
V_{GS_C}		20	gate-source voltage of carrier driver	
GND		21	RF ground	

3. Ordering information

Table 3.	Ordering information
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Type number	Packag		
	Name	Description	Version
BLM9D0910-05AM		plastic thermal enhanced package; no leads; 20 terminals; body 7.0 x 7.0 x 0.98 mm	LGA-7x7-20-2

4. Block diagram



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage		-	65	V
V _{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-55	+125	°C
Tj	junction temperature	<u>[1]</u>	-	175	°C
T _{case}	case temperature	[1]	-	125	°C

[1] Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

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6. Thermal characteristics

Table 5. Thermal characteristics

Measured for total device.

Symbol	Parameter	Conditions	Value	Unit
R _{th(j-c)}	thermal resistance from junction to	$T_{case} = 80 \ ^{\circ}C; \ P_{L(AV)} = 0.63 \ W$ [1]	8.1	K/W
	case	$T_{case} = 80 \ ^{\circ}C; \ P_{L(AV)} = 1 \ W$ [1]	6.3	K/W

[1] When operated with CW signal.

7. Characteristics

Table 6. DC characteristics

 $T_{case} = 25 \$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
Carrier	Carrier								
V _{GSq}	gate-source quiescent voltage	V _{DS} = 28 V; I _D = 15 mA	1.65	2.2	2.75	V			
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V/}{-5} \text{ V}; \text{ V}_{DS} = 0 \text{ V}$	-	-	140	nA			
Peaking	Peaking								
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V/}{-5} \text{ V}; \text{ V}_{DS} = 0 \text{ V}$	-	-	140	nA			
Final stages									
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 60 V	-	-	1.4	μA			
Driver stages									
I _{DSS}	drain leakage current	$V_{GS} = 0 V; V_{DS} = 60 V$	-	-	1.4	μA			

Table 7. RF Characteristics

Typical RF performance at $T_{case} = 25 \text{ °C}$; $V_{DS} = 28 \text{ V}$; $I_{Dq} = 15 \text{ mA}$ (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.55 \text{ V}$; $P_L = 0.63 \text{ W}$; f = 0.96 GHz. Unless otherwise specified, measured in an Ampleon production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
Test signal: CW pulsed								
G _p	power gain		16.8	18	21	dB		
η _D	drain efficiency	$P_{L} = 0.63 W$	34	38.4	-	%		
RL _{in}	input return loss		-	-19	-12	dB		
P _{L(3dB)}	output power at 3 dB gain compression		36	37	-	dBm		

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8. Application information

Table 8. Typical performance

Test signal: 1-carrier W-CDMA; $T_{case} = 25 \text{ °C}$; $V_{DS} = 28 \text{ V}$; $I_{Dq} = 15 \text{ mA}$ (driver and final stages); test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability CCDF; unless otherwise specified, measured in an Ampleon 869 MHz to 960 MHz frequency band demo circuit.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
P _{L(3dB)}	output power at 3 dB gain compression	f = 869 MHz	[1]	-	37	-	dBm
η _D	drain efficiency	9 dB OBO (P _{L(AV)} = 28 dBm); f = 869 MHz		-	40	-	%
G _p	power gain	P _{L(AV)} = 28 dBm; f = 869 MHz		-	18.5	-	dB
G _{flat}	gain flatness	P _{L(AV)} = 28 dBm; f = 869 MHz to 960 MHz		-	0.8	-	dB
ACPR _{5M}	adjacent channel power ratio (5 MHz)	P _{L(AV)} = 28 dBm; f = 869 MHz		-	-33	-	dBc
$\Delta G / \Delta T$	gain variation with temperature	f = 869 MHz		-	0.02	-	dB/∘C
К	Rollett stability factor	$T_{case} = -40 \text{ °C}; f = 0.15 \text{ GHz to}$ 5 GHz	[2]	-	>1	-	

[1] Pulsed CW power sweep measurement (δ = 10 %, t_p = 100 µs).

[2] S-parameters measured in a demo circuit.

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Printed-Circuit Board (PCB): Rogers 4350B; $\varepsilon_r = 3.66$; thickness = 0.508 mm; thickness of copper plating = 35 µm.

Fig 3. **Component layout**

Table 9. Demo test circuit list of components

See Figure 3 for component layout.

Component	Description	Value	Remarks
C1, C2, C3, C4, C5	multilayer ceramic chip capacitor	1μF [1	
C6	multilayer ceramic chip capacitor	1 μF [2	
X1	current sense resistor	100 mΩ, 1 W	Y44870R10000B0R

[1] American Technical Ceramics type 600F or capacitor of same quality.

[2] Murata or capacitor of same quality.

8.1 Ruggedness in a Doherty operation

The BLM9D0910-05AM is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 V$; I_{Dq} = 15 mA (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.55$ V; P_i corresponding to $P_{L(1dB)}$ under $Z_S = 50 \Omega$ load; f = 869 MHz (CW); $T_{case} = 25$ °C.

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8.2 Graphical data

BLM9D0910-05AM

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9. Package outline



Fig 8. Package outline LGA-7x7-20-2 (sheet 1 of 2)

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LGA-7x7-20-2

			Dra	awing Notes		
		Iten	n	Description		
		1	M	etal thickness of solder pads. ss with respect to exposed metal		
		2	Flathe	ess with respect to exposed metal		
1						
1						
1						
\vdash	Package outline drawing:		Tolerances ur	less otherwise stated:	Revision:	2
1	r aonago oatinio arawing.	units in mm.	Dimension: ±		Revision date:	30-Dec-19
1	LGA-7x7-20-2			Third angle projection		
				minu angle projection	Sheet 2 of 2	

Fig 9. Package outline LGA-7x7-20-2 (sheet 2 of 2)

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10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	1C [2]

 $\label{eq:constraint} \begin{tabular}{ll} [1] & CDM \ classification C2A \ is granted to any part that passes after exposure to an ESD pulse of 500 \ V. \end{tabular}$

[2] HBM classification 1C is granted to any part that passes after exposure to an ESD pulse of 1000 V.

11. Abbreviations

Table 11. Abbreviations				
Acronym	Description			
3GPP	3rd Generation Partnership Project			
CCDF	Complementary Cumulative Distribution Function			
CW	Continuous Wave			
DPCH	Dedicated Physical CHannel			
ESD	ElectroStatic Discharge			
GEN9	Ninth Generation			
GSM	Global System for Mobile Communications			
LDMOS	Laterally Diffused Metal Oxide Semiconductor			
LTE	Long Term Evolution			
MMIC	Monolithic Microwave Integrated Circuit			
MTF	Median Time to Failure			
NR	New Radio			
ОВО	Output Back Off			
PAR	Peak-to-Average Ratio			
RoHS	Restriction of Hazardous Substances			
VBW	Video Bandwidth			
VSWR	Voltage Standing Wave Ratio			
W-CDMA	Wideband Code Division Multiple Access			

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12. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLM9D0910-05AM v.2	20210129	Product data sheet	-	BLM9D0910-05AM v.1
Modifications:	<u>Table 8 on page 5</u> : changed value first row from 28 dBm to 37 dBm			
BLM9D0910-05AM v.1	20201013	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 29 January 2021 Document identifier: BLM9D0910-05AM